# Design of a K-Band Beamformer for Receiving Active Phased Array Anetennas for satellite communications 

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#### Abstract

In this paper, a Beamformer IC for receiving active phased-array antennas operating in the K-band for satellite communication was designed using the $65 \mathrm{~nm} 1 \mathrm{P9M}$ CMOS process. The designed beamformer consists of a Low Noise Amplifier (LNA), Phase Shifter (PS), Loss Compensation Amplifier (LCA), Digital Step Attenuator (DSA), and LCA in that order. The input of the beamformer was initially designed in a single-ended structure, considering the antenna's interface, but later internal circuits were designed in a differential structure using balun to enhance noise cancellation.

The LNA consists of a total of 3 stages, and the final stage was designed as a buffer stage with matching for PS. Since the input of the beamformer is the input of LNA, it was designed in a single-ended structure and converted to a differential structure by balun. Even after a received signal went through the differential structure, performance degradation was inevitable due to mismatches. So, we matched the impedance by balun, cross-coupled capacitor that appears to be a negative capacitance for increasing stability and a degeneration inductor for noise matching. The designed LNA achieves a measured gain of 23.8 dB and a noise figure of 4.2 dB .

The phase value of the PS was made to be adjustable from 0 to $357.2^{\circ}$ in increments of $2.8^{\circ}$, and three additional tuning bits were added. For phase changes below $11.25^{\circ}$, which are relatively small, a simplified T-type PS that removed the very small inductor and series switch transistor from a general T-type PS was used, and for phase changes above $22.5^{\circ}$, a modified bridged T-type PS that a capacitor was added on the control transistor side of the general bridged T-type PS was employed. As a result, the PS was able to reduce loss and parasitic capacitance, and enable wideband characteristic. Furthermore, the removal of the inductors enabled a smaller chip area.


The LCA for loss compensation consists of a 2-stage gain stage and a buffer stage for matching with the next stage. The 2-stage gain compensation structure with two general Cascode amplifier structure was designed.

The attenuation value of the designed DSA can be varied from o to 31.5 dB in 0.5 dB increments, and three 0.25 dB tuning bits were added. When the attenuation is below 2 dB , a simplified T-type attenuator structure was designed by removing the two very small series resistors from exiting T-type attenuator's input and output respectively. As a result, the control transistor also was unnecessary. For attenuation of 4 dB or more, a modified Pi-type attenuator structure was used to compensate for phase variation by adding a capacitor on the source side of the transistor in a shunt configuration, thus canceling out the pole and zero. For a 16 dB attenuator, two 8 dB attenuators were used for wideband characteristics.

The measured results show that beamformer gives the power gain of $30 \mathrm{~dB}, \mathrm{OP} 1 \mathrm{~dB}$ of $10 \mathrm{dBm}, I P 1 \mathrm{~dB}$ of -30 dBm , and NF of 5.3 dB . The total Beamformer consumes 92.5 mW from a 1.2 V supply and occupies $4,280 \times 800 \mu \mathrm{~m}^{2}$.

Keywords-CMOS, K-Band, Receiver, RX, Satellite, LNA, LCA, PS, DSA, Beamformer
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